T. Ni	umber	Hits	Search Text	DB	Time stamp
1	4.0002	84852		USPAT;	2002/12/04 07:58
_			, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	
				EPO; JPO;	
				DERWENT;	
				IBM TDB	
2		415	(dielectric adj (layer or film)) and	USPĀT;	2002/12/04 10:23
-			((dielectric adj constant) same (convers\$3	US-PGPUB;	=====================================
			or convert\$3))	EPO; JPO;	
				DERWENT;	
		. "	** · ;	IBM TDB	
3		299	((dielectric adj (layer or film)) and	USPAT;	2002/12/04 08:07
			((dielectric adj constant) same (convers\$3	US-PGPUB;	
			or convert\$3))) and semiconductor	EPO; JPO;	
				DERWENT;	
				IBM TDB	
4		169	(((dielectric adj (layer or film)) and	USPAT;	2002/12/04 08:07
			((dielectric adj constant) same (convers\$3	US-PGPUB;]
			or convert\$3))) and semiconductor) and	EPO; JPO;	
			("438")	DERWENT;	
				IBM TDB	
5		87	(dielectric adj (layer or film)) and	USPĀT;	2002/12/04 08:25
			((first adj dielectric adj constant) same	US-PGPUB;	
			(second adj dielectric adj constant))	EPO; JPO;	
				DERWENT;	
1				IBM_TDB	
6		2	(dielectric adj (layer or film)) and	USPAT;	2002/12/04 10:24
1			((dielectric adj constant) same	US-PGPUB;	
			((convers\$3 or convert\$3) adj (dielectric	EPO; JPO;	
			adj constant)))	DERWENT;	
1				IBM_TDB	
-	-	394	(438/240).CCLS.	USPAT;	2001/11/06 14:29
	1			EPO; JPO;	
				DERWENT	
] -		204	(438/243).CCLS.	USPAT;	2002/05/21 14:04
				EPO; JPO;	
	- 1	83	(438/246).CCLS.	DERWENT	2001 (11 (06 14 20
-		03	(436/246).CCLS.	USPAT; EPO; JPO;	2001/11/06 14:30
	1			DERWENT	
_		37	(438/247).CCLS.	USPAT;	2001/11/06 14:30
	1	3,	(130/21//.0020.	EPO; JPO;	201/11/100 14.50
				DERWENT	
-	- 1	218	(438/386).CCLS.	USPAT;	2001/11/06 14:30
				EPO; JPO;	
				DERWENT	
-		84	(438/387).CCLS.	USPAT;	2001/11/06 14:30
				EPO; JPO;	
	İ			DERWENT	
-		55	(438/389).CCLS.	USPAT;	2001/11/06 14:30
				EPO; JPO;	
}				DERWENT	
-		28	(438/390).CCLS.	USPAT;	2001/11/09 11:10
				EPO; JPO;	18
			(420 (044) - 557 0	DERWENT	_ D
_		107	(438/244).CCLS.	USPAT;	2001/11/16 15:23
				EPO; JPO;	
		_	(apropt) add (final 111	DERWENT	0001/11/55 15 5
-		2	(cover\$3 adj3 (first adj1 area)) and	USPAT	2001/11/16 15:28
_		2	(first adj1 dielectric)	IICDAM	2001/11/16 15 22
	1	4	((cover\$3 adj3 (first adj1 area)) and (first adj1 dielectric)) and (second adj1	USPAT	2001/11/16 15:29
	-		dielectric) and (second adjl		
_		155	cover\$3 adj3 (first adj1 area)	iic D v a	2001/11/19 08:46
_		155	cover\$3 adj3 (first adj1 area)	USPAT USPAT	2001/11/19 08:46
_		5997		USPAT	2001/11/19 08:49
_		2	(first adj1 dielectric) and (cover\$3 adj3	USPAT	2002/03/21 14:37
			(first adjl area))		2302, 22, 23
		217	first adj1 dielectric adj1 constant	USPAT	2001/11/19 08:51
			and the same of th		

-	0	((and a	2001/11/19 0	8:54
		(second adj1 dielectric adj1 constant))		
		and ((E-beams) or (I-beams) or (amine))		İ
-	0		2001/11/19 0	8 - 54
		(second adj1 dielectric adj1 constant))		
		and (E-beams)		
_	0		2001/11/19 0	0. 54
-			2001/11/19 0	5:54
		(second adj1 dielectric adj1 constant))		
	_	and (I-beams)		
-	0	((first adj1 dielectric adj1 constant) and USPAT	2001/11/19 0	8:54
		(second adj1 dielectric adj1 constant))		
		and (amine)		
-	170	(first adj1 dielectric adj1 constant) and USPAT	2001/11/19 0	9:16
		(second adj1 dielectric adj1 constant)	,	
<u>-</u>	1557	438/240,244,238,239,243,246,247,386,389,390, BETPATCLS.	2002/12/03 1	4.18
1_	0	438/240,244,238,239,243,246,247,386,389,390, BSPATcls.	2002/12/03 14	
		and (I-beams)	2002/12/03 1.	1.21
	,		0000 (00 (00 0	
-	1		2001/11/19 13	1:19
	_	and (e-beams)		
-	7		2001/11/19 09	9:19
	1	and (amine)		
-	0	(438/240,244,238,239,243,246,247,386,389,390µ38PATccls.	2001/11/19 09	9:24
		and (amine)) and (first adjl dielectric)		
-	0	(438/240,244,238,239,243,246,247,386,389,390µ\$\text{PATccls}.	2001/11/19 09	9:20
		and (e-beams)) and (first adjl dielectric)		20
_	148		2001/11/19 09	3.20
	140	and (first adj1 dielectric)	2001/11/19 05	2:2U
	110		0001/11/10	, , ,
-	118	(438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390 USPATccls.	2001/11/19 09	1:20
		and (first adj1 dielectric)) and (second		1
		adj1 dielectric)		
-	0	((438/240,244,238,239,243,246,247,386,389,390SPAT.ccls.	2001/11/19 09	3:21
		and (first adj1 dielectric)) and (second		
	1	adj1 dielectric)) and (amine)		
_	0		2001/11/19 09	3.54
		and (first adjl dielectric)) and (second	2001/11/15 01	/. 54
		adj1 dielectric)) and (E-beams)		1
_	0		2001/11/19 09	2.21
		and (first adj1 dielectric)) and (second	2001/11/19 05	,:21
	_	adjl dielectric)) and (I-beams)		
-	0	((438/240,244,238,239,243,246,247,386,389,39@SP&T.ccls.	2001/11/19 09):21
		and (first adj1 dielectric)) and (second		
		adj1 dielectric)) and (I adj1 beams)		
-	0	(2001/11/19 09):21
		and (first adj1 dielectric)) and (second		
1		adj1 dielectric)) and (E adj1 beams)		
-	0		2001/11/19 00	24
		and (amine)) and (second adj1 dielectric	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	1
		adj1 constant)		
l _	0	(438/240,244,238,239,243,246,247,386,389,390µ\$\Patcls.	2001/11/19 09	
			2001/11/19 09	. 24
_	0	and (amine)) and (first adjl dielectric	0000 (05 (05	
	0	4d43860A6t2At)238,239,243,246,247,386,389,39USPAT.ccls.	2002/05/21 14	:38
	[and (first adj1 dielectric)) and (second		
	_	adj1 dielectric)) and (Electron adj1		
_	0	beam8/240,244,238,239,243,246,247,386,389,390SPAT.ccls.	2001/11/19 09	:54
		and (first adj1 dielectric)) and (second		-
		adj1 dielectric)) and (Electronic adj1		
-	0	beam8/240,244,238,239,243,246,247,386,389,390SPAT.ccls.	2001/11/19 09	:55
		and (first adj1 dielectric)) and (second		
		adjl dielectric)) and (ions adjl beams)		
_	0	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 39USPAT.ccls.	2001/11/10 00	. E.C.
		and (first adjl dielectric)) and (second	2001/11/19 09	: 56
	[and (title duji dielectric)) and (second		1
_	, ,	adj1 dielectric)) and (hydrogen adj1		_
_	0	\$438\(\delta\) 840\(\delta\) 8	2001/11/19 09	:56
		and (first adjl dielectric)) and (hydrogen		
		adj1 silsesquioxane)		
_	3	((438/240,244,238,239,243,246,247,386,389,390SPAT.ccls.	2001/11/19 10	:11
i		and (first adj1 dielectric)) and (second		1
		adj1 dielectric)) and (oxygen adj1 plasma)		1
-	1	("6110842").PN. USPAT	2001/11/19 10	:11
-	6	("4764248" "4980307" "5672521" USPAT	2001/11/19 10	
		"5763922" "5834351" "5937310").PN.		-

-	1 2	,	USPAT	2001/11/19 11:31
1 _		("5652173" "5770509").PN. ("5928960").PN.	USPAT	2001/11/19 11:20 2001/11/19 11:31
-	281			2002/05/21 14:07
-	201	(430/300).CCLS.	USPAT; US-PGPUB;	2002/03/21 14:07
			EPO; JPO;	
			DERWENT;	
	1		IBM TDB	
	31	(438/390).CCLS.	USPAT;	2002/05/21 14:07
-	31	(438/390).ССБ3.	US-PGPUB;	2002/03/21 14:07
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	59	(438/389).CCLS.	USPAT;	2002/05/21 14:16
_		(430/303).0013.	US-PGPUB;	2002/03/21 14.10
			EPO; JPO;	
			DERWENT;	
	}		IBM TDB	
_	43	(438/247).CCLS.	USPAT;	2002/05/21 14:35
	13	(430/247).0003.	US-PGPUB;	2002/03/21 14.33
			EPO; JPO;	
1			DERWENT;	
			IBM TDB	
_	96	(438/246).CCLS.	USPAT;	2002/05/21 14:51
	30	(430/240/:0005.	US-PGPUB;	2002/05/21 14.51
7			EPO; JPO;	F I
			DERWENT;	
			IBM TDB	
	113	(438/387).CCLS.	USPAT;	2002/05/21 15:04
	113	(430/307/:0010:	US-PGPUB;	2002/03/21 13.04
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	164	(438/244).CCLS.	USPAT;	2002/05/21 15:11
	101	(130/214).0000.	US-PGPUB;	2002/03/21 13.11
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	281	(438/386).CCLS.	USPAT;	2002/05/22 07:40
		(100,000,100201	US-PGPUB;	2002/03/22 07:40
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	273	(438/243).CCLS.	USPAT;	2002/05/22 08:12
		, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	2002,00,22 00.12
			EPO; JPO;	
	V Val		DERWENT;	
			IBM TDB	_ 1
_	2429	438/240,244,238,239,243,246,247,386,389,390		2002/12/03 14:34
		. , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	1 , -2 , 00 1
			EPO; JPO;	
	1		DERWENT;	
			IBM TDB	
_	27	438/240,244,238,239,243,246,247,386,389,390		2002/12/03 14:22
		and (I-beams or E-beam)		
_	31	438/240,244,238,239,243,246,247,386,389,390	BSTPATC1s.	2002/12/03 14:22
		and (I-beams or E-beam)	US-PGPUB;	
		·	EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	2428	438/240,244,238,239,243,246,247,386,389,390		2002/12/03 14:47
		. , .,,,,,,,,,,	US-PGPUB	
_	84852	dielectric adj (layer or film)	USPAT;	2002/12/03 14:55
		J . J	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	

	13087	1 (4:-)	TIGD20	1 2000 /10 /02 14 56
_	13087	,	USPAT;	2002/12/03 14:56
		(convers\$3 or convert\$3)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	7979	((dielectric adj (layer or film)) and	USPAT;	2002/12/03 14:56
		(convers\$3 or convert\$3)) and	US-PGPUB;	
		semiconductor	EPO; JPO;	
			DERWENT;	
			IBM TDB	
l _	3203	(((dielectric adj (layer or film)) and	USPAT;	2002/12/03 14:56
	0200	(convers\$3 or convert\$3)) and	US-PGPUB;	2002, 12, 00 21100
		semiconductor) and ("438")	EPO; JPO;	
		Semiconductory and (450)	DERWENT;	
			IBM TDB	
	909	///diplostric add /lawar or film)) and	USPAT;	2002/12/03 14:56
-	909	, , , , , , , , , , , , , , , , , , ,		2002/12/03 14:56
		(convers\$3 or convert\$3)) and	US-PGPUB;	
		semiconductor) and ("438")) and	EPO; JPO;	
		(dielectric adj constant)	DERWENT;	
			IBM_TDB	
-	84852	dielectric adj (layer or film)	USPĀT;	2002/12/04 07:57
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	A [11]		IBM TDB	
_	13087	(dielectric adj (layer or film)) and	USPAT;	2002/12/03 14:56
		(convers\$3 or convert\$3)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	7979	((dielectric adj (layer or film)) and	USPAT;	2002/12/03 14:56
		(convers\$3 or convert\$3)) and	US-PGPUB;	
94		semiconductor	EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	3203	(((dielectric adj (layer or film)) and	USPAT;	2002/12/03 14:56
45	3203	(convers\$3 or convert\$3)) and	US-PGPUB;	2002/12/03 14:56
		semiconductor) and ("438")	EPO; JPO;	
			DERWENT;	
	000	////44-1	IBM_TDB	0000/10/00 11 55
_	909	••••	USPAT;	2002/12/03 14:57
		(convers\$3 or convert\$3)) and	US-PGPUB;	
		semiconductor) and ("438")) and	EPO; JPO;	
		(dielectric adj constant)	DERWENT;	
			IBM_TDB	